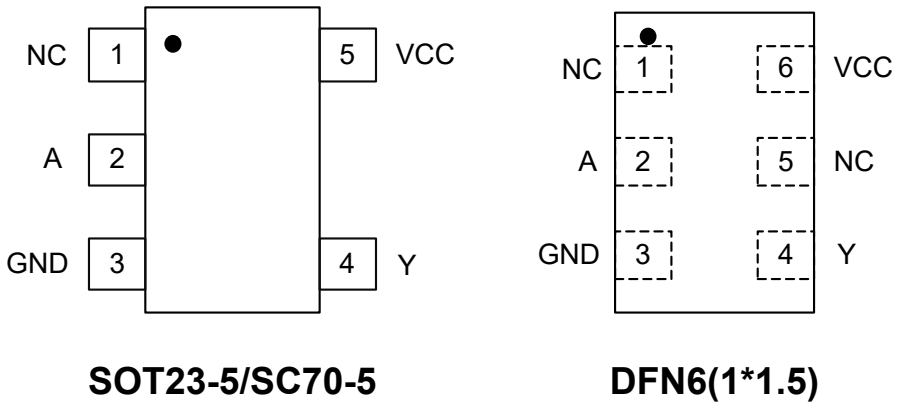
1.Description

The 74AUP1G04 is a high performance single inverter operating from 0.8V to 3.6V supply. This device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive.

2.Features

- Designed for 0.8V to 3.6V V_{CC} Operation
- Low static power consumption; I_{CC}=0.7μA (maximum)
- 4mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- These Devices are Pb−Free and are RoHS Compliant
- Tiny SC70-5, SOT23-5 and DFN6(1.0×1.5) Packages

3.Pinning information



SOT23-5/SC70-5 **DFN6(1*1.5)**

Figure1. Top View

4.Pin Function

SC70-5/ SOT23-5

Pin No.	Pin Name	Function
1	NC	No connect
2	A	Input
3	GND	Ground
4	Y	Output
5	VCC	Supply Voltage

DFN6

Pin No.	Pin Name	Function
1	NC	No connect
2	A	Input
3	GND	Ground
4	Y	Output
5	NC	No connect
6	VCC	Supply Voltage

5.Block Diagram

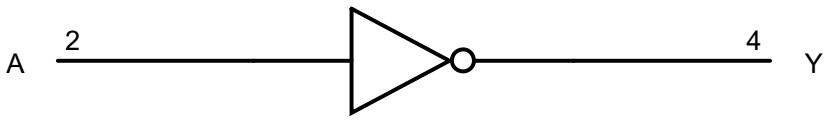


Figure2. Logic Symbol

Function Table

Input	Output
A	**Y**
L	H
H	L

6.Absolute Maximum Ratings

Parameter		Symbol	Value	Units
DC Supply Voltage		V_{CC}	−0.5 to 4.6	V
DC Input Voltage		V_I	$-0.5 \le V_I \le +4.6$	V
DC Output Voltage Output in Higher or Low State (1)		V_O	−0.5 to 4.6	V
DC Input Diode Current V_I<GND		I_{IK}	-50	mA
DC Output Diode Current V_O<GND, V_O>V_{CC}		I_{OK}	±50	mA
DC Output Sink Current		I_O	±20	mA
DC Supply Current per Supply Pin		I_{CC}	±50	mA
Storage Temperature Range		T_{STG}	-65 to 150	°C
Lead Temperature, 1 mm from Case for 10 Seconds		T_L	260	°C
Max Junction Temperature		T_J	150	°C
ESD Classification	Human Body Model (2)	V_{ESD}	±4000	V
	Charged Device Model (3)		±1000	V
Max Latch up Current Above V_{CC} and GND at 125°C (4)		I_{LU}	±100	mA

7.Thermal Characteristics

Ratings	Package	Symbol	Value	Units
Thermal Characteristics, Thermal Resistance, Junction-to-Air	SC70-5	$R_{\theta JA}$	300	°C/W
	SOT23-5		250	
	DFN6(1.0x1.5)		440	
Power Dissipation in Still Air at 85°C	SC70-5	P_D	215	mW
	SOT23-5		260	
	DFN6(1.0x1.5)		150	

8.Recommended Operating Conditions

Parameter		Symbol	Min	Max	Unit
DC Supply Voltage Operating		V_{CC}	0.8	3.6	V
DC input Voltage		V_{IN}	0	3.6	V
DC Output Voltage (High or Low State)		V_{OUT}	0	3.6	V
Operating Temperature Range		T_A	-40	85	°C
Input Rise and Fall Time	V_{CC}=0.8V to 3.6V	t_r, t_f	0	20	ns/V

Notes:

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied.

9.Electrical Characteristics

DC Electrical Characteristics

Parameter	Condition	Symbol	V_{CC}(V)	T_A=25°C			−40°C≤T_A≤85°C		Units
				Min	Typ	Max	Min	Max	
High−Level Input Voltage		V_{IH}	0.8V	0.75V_{CC}			0.75V_{CC}		V
			0.9 to 1.95	0.7V_{CC}			0.7V_{CC}		
			2.3 to 2.7	1.6			1.6		
			3 to 3.6	2			2		
Low−Level Input Voltage		V_{IL}	0.8			0.25V_{CC}		0.25V_{CC}	V
			0.9 to 1.95			0.3V_{CC}		0.3V_{CC}	
			2.3 to 2.7			0.7		0.7	
			3.0 to 3.6			0.9		0.9	
High−Level Output Voltage	I_{OH}=−20μA	V_{OH}	0.8 to 3.6	V_{CC}-0.1			V_{CC}-0.1		V
	I_{OH}=−1.1mA		1.1	0.82	1.02		0.77		
	I_{OH}=−1.7μA		1.4	1.11	1.32		1.03		
	I_{OH}=−1.9mA		1.65	1.32	1.58		1.30		
	I_{OH}=−2.3mA		2.3	2.05	2.24		1.97		
	I_{OH}=−3.1mA			1.9	2.22		1.85		
	I_{OH}=−2.7mA		3	2.72	2.95		2.67		
	I_{OH}=−4.0mA			2.6	2.92		2.55		
Low−Level Output Voltage	I_{OL}=20μA	V_{OL}	0.8 to 3.6			0.1		0.1	V
	I_{OL}=1.1mA		1.1		0.11	0.33		0.33	
	I_{OL}=1.7mA		1.4		0.12	0.31		0.37	
	I_{OL}=1.9mA		1.65		0.11	0.31		0.35	
	I_{OL}=2.3mA		2.3		0.14	0.31		0.33	
	I_{OL}=3.1mA				0.19	0.44		0.45	
	I_{OL}=2.7mA		3		0.11	0.31		0.33	
	I_{OL}=4.0mA				0.16	0.44		0.45	

Input Leakage Current	V_{IN}=V_{CC} or GND	I_{IN}	0 to 3.6			0.1		0.2	μA
Power Off Leakage Current	V_{IN}=3.6V or V_{OUT}=3.6V	I_{OFF}	0			0.2		0.5	μA
Quiescent Supply Current	V_{IN}=3.6V or GND	I_{CC}	3.6			0.2		0.7	μA

10.AC Electrical Characteristics

$t_r = t_f$ = 2.5ns

Parameter	Condition	Symbol	V_{CC}(V)	T_A=25°C			−40°C≤T_A≤85°C		Units
				Min	Typ	Max	Min	Max	
Propagation Delay (Figure3 And 4)	C_L=5pF (5)	t_{PHL} t_{PLH}	0.8		15.6				ns
			1 2	3.3	5.9	10.8	2.1	13.5	
			1.5	2.5	4.2	7	1.6	8.8	
			1.8	2.2	3.4	5.9	1.4	7	
			2.5	1.7	2.5	4	1.3	4.9	
			3.3	1.4	2.1	3.2	1.2	3.9	
	C_L=10pF (5)		0.8		17.7				ns
			1.2	3.9	6.9	12.2	3.1	15	
			1.5	3	5	8.1	2.5	9.9	
			1.8	2.6	4	6.9	2.1	7.9	
			2.5	2.1	3	4.6	1.7	5.6	
			3.3	1.8	2.5	3.8	1.5	4.5	
	C_L=15pF (5)		0.8		19.5				ns
			1.2	4.7	7.8	13	3.8	15.9	
			1.5	3.7	5.6	8.6	3.1	10.6	
			1.8	3.2	4.6	7.4	2.6	8.5	
			2.5	2.5	3.5	5.1	2.1	6.1	
			3.3	2.2	2.9	4.2	1.9	5	
	C_L=30pF (5)		0.8		25.4				ns
			1.2	6.8	10.4	16	6.1	19	
			1.5	5.3	7.6	10.8	4.8	12.9	
			1.8	4.6	6.3	9.2	4.1	10.5	
			2.5	3.6	4.8	6.5	3.3	7.6	
			3.3	3.2	4	5.4	2.9	6.2	

Notes: (5) C_L includes probe and jig capacitance.

11.Capacitance Characteristics

Parameter	Symbol	Condition		Typ	Units
Input Capacitance	C_{IN}	V_{CC}=3.6V, V_I= 0 V or V_{CC}		2	pF
output capacitance	C_O	V_{CC}= 0V, V_{OUT}=GND		3	pF
Power Dissipation Capacitance (6)	C_{PD}	1MHz, V_I=0 V to V_{CC}	V_{CC}=0.8V	7.6	pF
			V_{CC}=1.2V	8.1	
			V_{CC}=1.5V	8.5	
			V_{CC}=1.8V	8.6	
			V_{CC}=2.5V	9	
			V_{CC}=3.3V	9.6	

Notes:

(6) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)}=C_{PD}\times V_{CC}\times f_{in}+I_{CC}\times C_{PD}$ is used to determine the no−load dynamic power consumption; $P_D=C_{PD}\times V_{CC}^2\times f_{in}+I_{CC}\times V_{CC}\times$Fig.

12.Waveform and Test Circuit

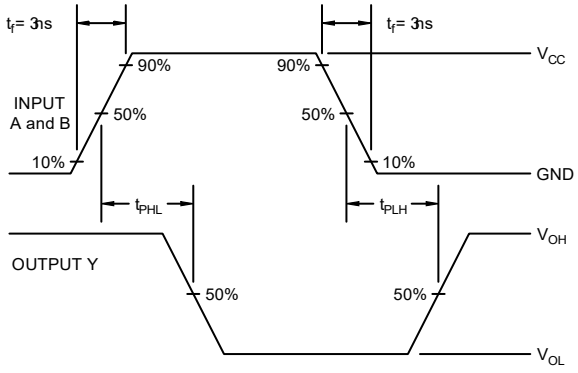


Figure3. Switching Waveform

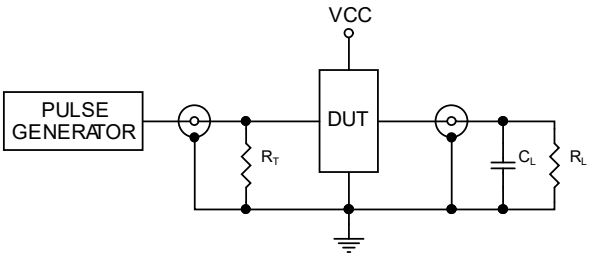
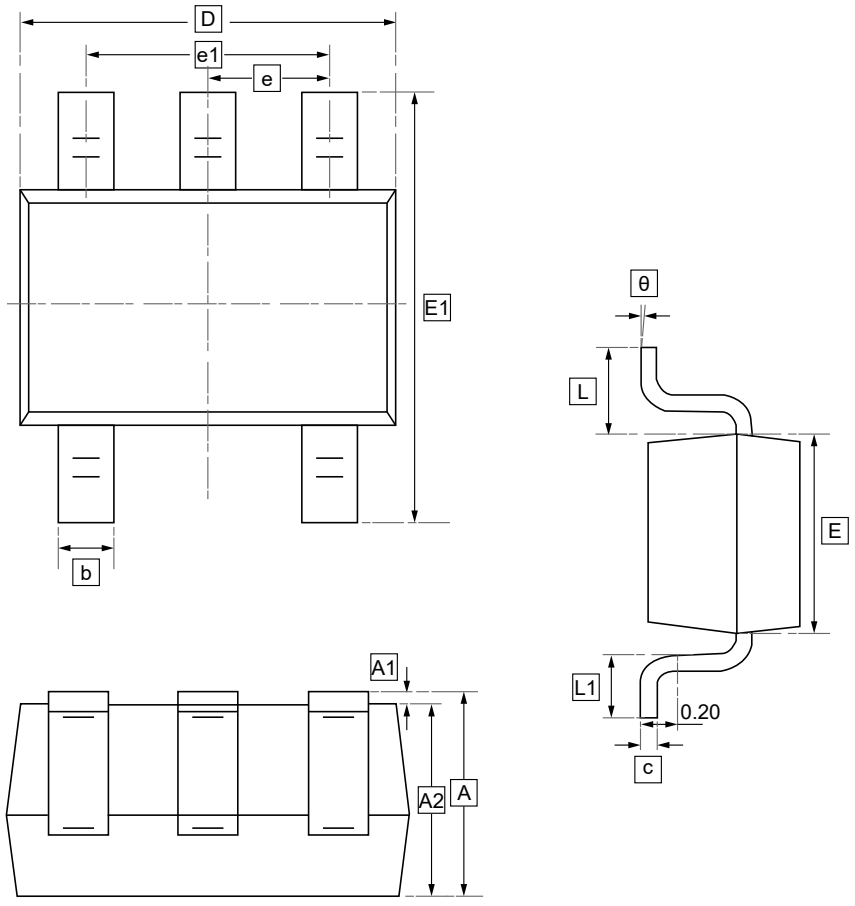


Figure4. Test Circuit

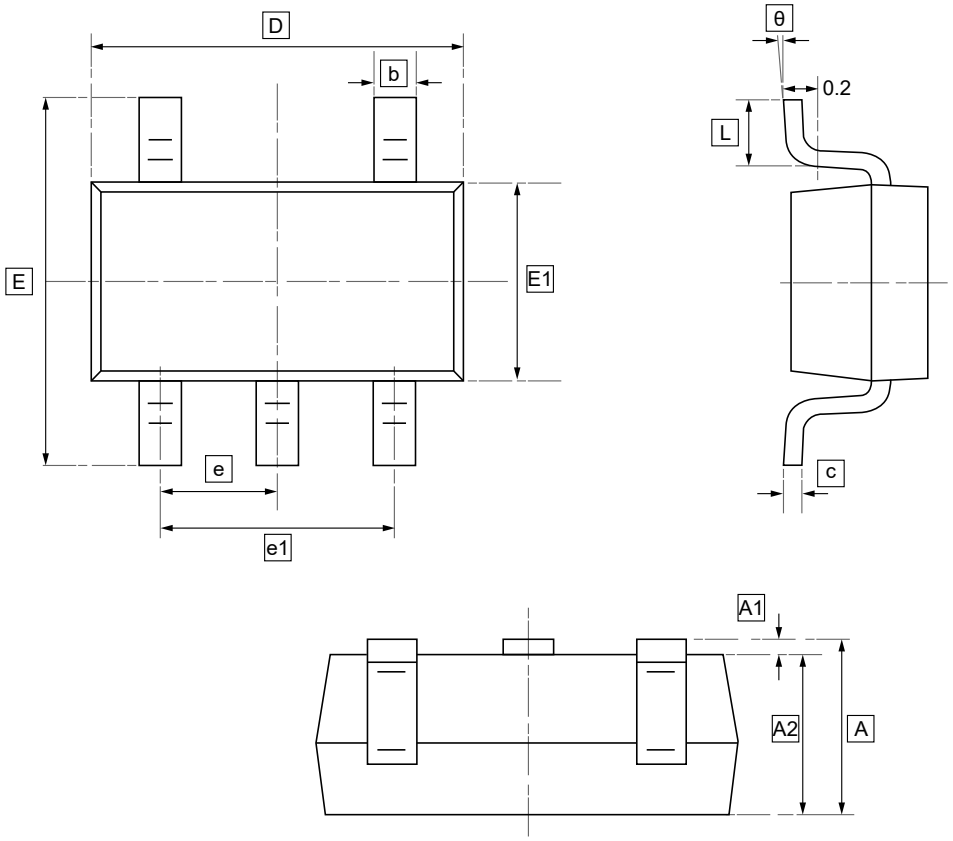
13.1 SC70-5 Package Outline Dimensions



DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	b	c	D	E	E1	e	e1	L	θ
Min	0.90	0.00	0.90	0.15	0.08	1.80	1.15	2.15	0.65	1.20	0.26	7°
Max	1.10	0.10	1.00	0.35	0.15	2.25	1.35	2.45	TYP	1.40	0.46	REF.

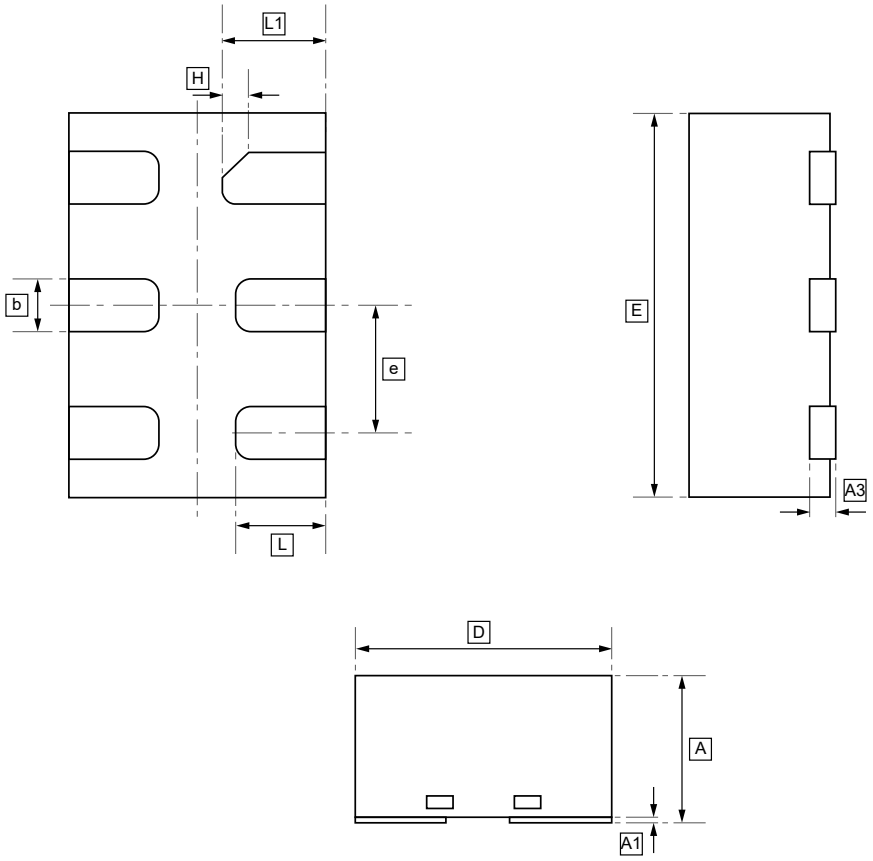
13.2 SOT-23-5 Package Outline Dimensions



DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	b	c	D	E1	E	e	e1	L	θ
Min	1.050	0.000	1.050	0.300	0.100	2.820	1.500	2.650	0.950	1.800	0.300	0°
Max	1.250	0.100	1.150	0.500	0.200	3.020	1.700	2.950	BSC	2.000	0.600	8°

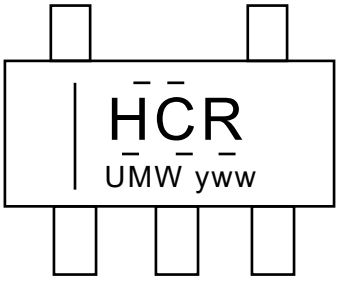
13.3 DFN6(1*1.5) Package Outline Dimensions



DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A3	b	D	E	e	H	L	L1
Min	0.50	0	0.10	0.15	0.90	1.40	0.40	0.10	0.30	0.35
Max	0.60	0.05	REF	0.25	1.10	1.60	0.60	REF	0.40	0.45

14.Ordering Information



yww: Batch Code

Order Code	Marking	Package	Base QTY	Delivery Mode
UMW SN74AUP1G04DCKR	HCR	SC70-5	3000	Tape and reel
UMW SN74AUP1G04DBVR	H04F	SOT23-5	3000	Tape and reel
UMW SN74AUP1G04DRYR	HC	DFN6(1*1.5)	5000	Tape and reel

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